DATA SHEET



SILICON POWER TRANSISTOR **2SA1843**

PNP SILICON EPITAXIAL POWER TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1843 is a power transistor developed for high-speed switching and features a high her at low Vce(sat). This transistor is ideal for use as a driver in DC/DC converters and actuators.

In addition, this transistor features a package that can be auto-mounted in radial taping specifications, thus contributing to mounting cost reduction.

FEATURES

- · Auto-mounting possible in radial taping specifications
- Resin-molded insulation type package with power rating of 1.8 W in stand-alone conditions
 High hre and low VcE(sat):
 VcE(sat) ≤ -0.3 V @ Ic = -3.0 A, IB = -0.15 A
 hre ≥ 100 @ VcE = -2.0 V, Ic = -1.0 A
 Fast switching speed

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vсво		-100	V
Collector to emitter voltage	Vceo		-60	V
Emitter to base voltage	VEBO		-7.0	V
Collector current (DC)	Ic(DC)		-5.0	Α
Collector current (pulse)	IC(pulse)	PW ≤ 300 μs, duty cycle ≤ 2%	-10	Α
Base current (DC)	I _{B(DC)}		-2.5	Α
Total power dissipation	Рт	Ta = 25°C	1.8	W
Junction temperature	Tj		150	°C
Storage temperature	T _{stg}		-55 to +150	°C

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

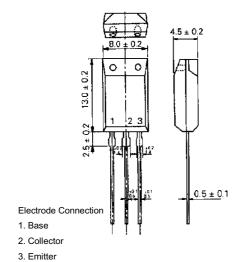
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = -60 V, IE = 0			-10	μΑ
Collector cutoff current	ICER	$V_{CE} = -60 \text{ V}, \text{ R}_{EB} = 50 \Omega$ $Ta = 125^{\circ}\text{C}$			-1.0	mA
Collector cutoff current	ICEX1	VCE = -60 V, VBE(off) = 1.5 V			-10	μΑ
Collector cutoff current	ICEX2	Vce = -60 V, Vbe(off) = 1.5 V Ta = 125°C			-1.0	mA
Emitter cutoff current	ІЕВО	V _{EB} = -5.0 V, I _C = 0			-10	μΑ
DC current gain	h _{FE1} *	Vce = -2.0 V, Ic = -0.5 A	100			-
DC current gain	h _{FE2} *	$V_{CE} = -2.0 \text{ V}, I_{C} = -1.0 \text{ A}$	100		400	I
DC current gain	h _{FE3} *	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -3.0 \text{ A}$	60			I
Collector saturation voltage	V _{CE(sat)1} *	Ic = -3.0 A, IB = -0.15 A			-0.3	V
Collector saturation voltage	V _{CE(sat)2} *	$I_C = -4.0 \text{ A}, I_B = -0.2 \text{ A}$			-0.5	V
Base saturation voltage	V _{BE(sat)1} *	Ic = -3.0 A, IB = -0.15 A	3	gio-	-1.2	V
Base saturation voltage	V _{BE(sat)2} *	Ic = -4.0 A, IB = -0.2 A		0	-1.5	٧
Gain bandwidth product	f⊤	Vce = -10 V, lc = -0.5 A	C	80		MHz
Collector capacitance	Соь	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	111	130		pF
Turn-on time	ton	Ic = -3.0 A		0.15		μs
Storage time	tstg	$I_{B1} = -I_{B2} = -0.15 \text{ A}$ $R_L = 17 \Omega, V_{CC} = -50 \text{ V}$		1.0		μs
Fall time	tf	- 17 32, VOO - 50 V		0.1		μs

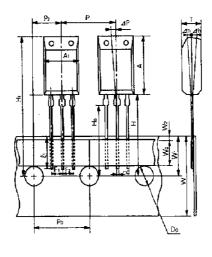
^{*} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

hfe CLASSIFICATION

Marking	М	L	K
hfe	100 to 200	150 to 300	200 to 400

PACKAGE DRAWING (UNIT: mm) TAPING SPECIFICATION

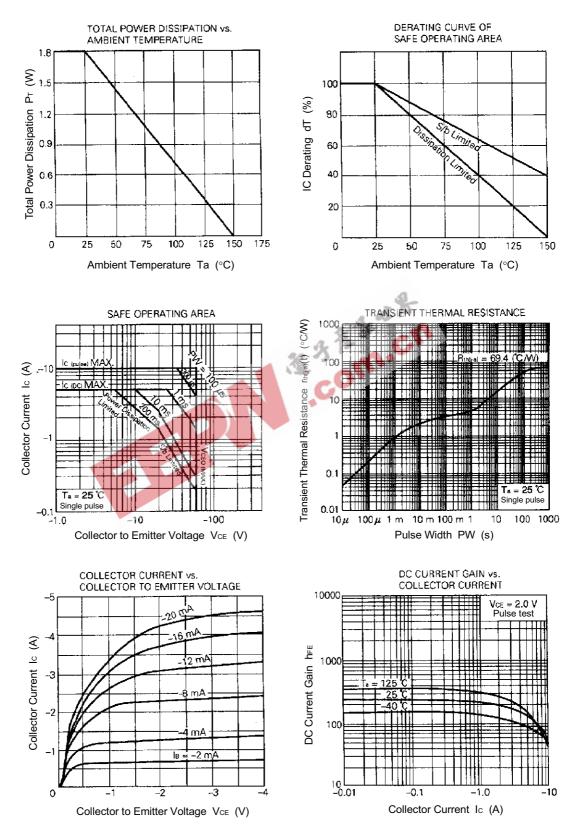




8.0 ± 0.2 13.0 ± 0.2 \$\phi 4.0 ± 0.2 0.5 ± 0.1 2.5
p4.0 ± 0.2 0.5 ± 0.1 2.5 ± 0.1 2.5 ± 0.1 2.5 ± 0.1 2.5 ± 0.1 20.0 MAX. 16.0 ± 0.5 32.2 MAX.
0.5 ± 0.1 2.5±0.1 2.5±0.1 2.5±0.1 20.0 MAX. 16.0 ± 0.5 32.2 MAX.
2.5±0.4 2.5±0.1 2.5±0.1 20.0 MAX. 16.0 ± 0.5 32.2 MAX.
2.5±0.1 20.0 MAX. 16.0 ± 0.5 32.2 MAX.
20.0 MAX. 16.0 ± 0.5 32.2 MAX.
16.0 ± 0.5 32.2 MAX.
32.2 MAX.
0.10
0 ± 1.0
2.5 MIN.
12.7 ± 1.0
12.7 ± 0.3
6.35 ± 0.5
0 ± 1.3
4.5 ± 0.2
18.0+0.5
5.0 MIN.
9.0 ± 0.5
0.7 MIN.

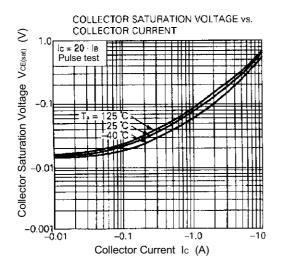


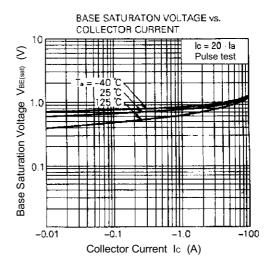
TYPICAL CHARACTERISTICS (Ta = 25°C)

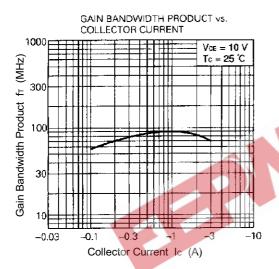


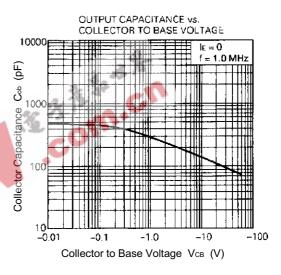
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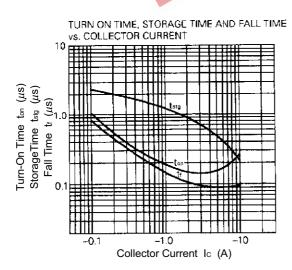
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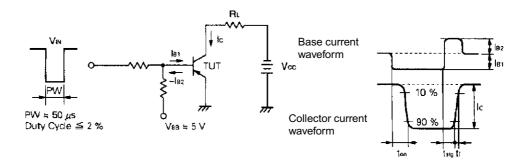








SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT





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